- Permits Digital Data Transmission Over Coaxial Cable, Strip Line, or Twisted Pair
- Operates With 50- $\Omega$  to 500- $\Omega$  Transmission Lines
- TTL Compatible With 5-V Supply
- 2.4-V Output at I<sub>OH</sub> = −75 mA
- Uncommitted Emitter-Follower Output Structure for Party-Line Operation
- IMPACT™ Low-Power Schottky Technology
- Improved Replacement for the SN75121 and Signetics 8T13
- Glitchless Power Up/Power Down
- Short-Circuit Protection
- AND-OR Logic Configuration
- High Speed . . . Maximum Propagation Delay Time of 14 ns at C<sub>L</sub> = 15 pF

#### description

The SN75ALS121 dual line driver is designed for digital data transmission over lines having impedances from 50 to 500  $\Omega$ . It is compatible with standard TTL logic and supply voltage levels.

#### **DORNPACKAGE** (TOP VIEW) 16 V<sub>CC</sub> 1A [ 1B 🛮 2 15 2F 1C **[**] 3 14 T 2E 13 2D 1D **∏** 4 12 T 2C 1E [ 5 11 2B 1F 10 2A 1Y **∏** 7 GND [ 9**∏** 2Y

#### NOT RECOMMENDED FOR NEW DESIGN

#### **FUNCTION TABLE**

INPUTS						OUTPUT
Α	В	С	D	Е	F	Υ
Н	Н	Н	Н	Χ	Х	Н
Х	Χ	Χ	Χ	Н	Н	Н
All other input combinations						L

H = high level, L = low level, X = irrelevant

The low-impedance emitter-follower outputs drive terminated lines such as coaxial cable, strip line, or twisted pair. Having the outputs uncommitted allows wired-OR logic to be performed in party-line applications. Output short-circuit protection is provided by an internal clamping network that turns on when the output voltage drops below approximately 1.5 V. All inputs are in conventional TTL configuration. Gating can be used during power-up and power-down sequences to ensure that no noise is introduced on the line.

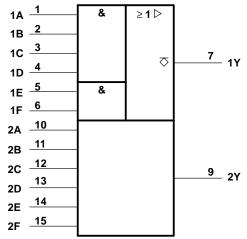
The SN75ALS121 employs the IMPACT™ process to achieve fast switching speeds, low power dissipation, and reduced input current requirements.

The SN75ALS121 is characterized for operation from 0°C to 70°C.

IMPACT is a trademark of Texas Instruments Incorporated.

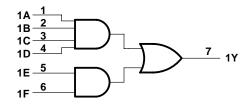


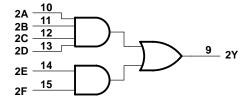
## logic symbol<sup>†</sup>



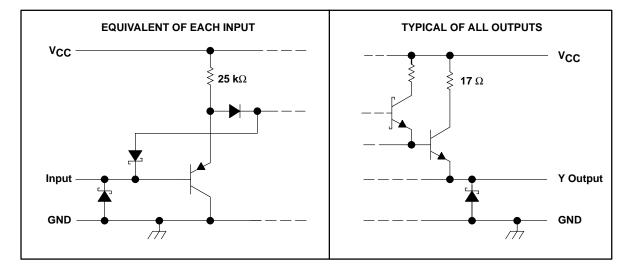
<sup>&</sup>lt;sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

# logic diagram (positive logic)





# schematics of inputs and outputs



# absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V <sub>CC</sub> (see Note 1)	6 V
Input voltage	6 V
Output voltage	6 V
Continuous total dissipation at (or below) 25°C free air temperature See Dissipation Rating 1	able
Operating free-air temperature range	70°C
Storage temperature range – 65°C to 15	50°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	30°C

NOTE 1: All voltage values are with respect to network ground terminal.

#### **DISSIPATION RATING TABLE**

$\begin{array}{cc} \text{PACKAGE} & \text{T}_{\text{A}} \leq 25^{\circ}\text{C} \\ \text{POWER RATING} \end{array}$		OPERATING FACTOR ABOVE T <sub>A</sub> = 25°C	T <sub>A</sub> = 70°C POWER RATING		
D	950 mW	7.6 mW/°C	608 mW		
N	1150 mW	9.2 mW/°C	736 mW		

#### recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V <sub>CC</sub>	4.75	5	5.25	V
High-level input voltage, VIH	2			V
Low-level input voltage, V <sub>IL</sub>			8.0	V
High-level output current, IOH			<b>–</b> 75	mA
Operating free-air temperature range, TA	0		70	°C

# electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS			MIN	TYP <sup>†</sup>	MAX	UNIT
٧ıK	Input clamp voltage	V <sub>CC</sub> = 5 V,	I <sub>I</sub> = -12 mA				- 1.5	V
V <sub>(BR)I</sub>	Input breakdown voltage	V <sub>CC</sub> = 5 V,	I <sub>I</sub> = 10 mA		5.5			V
Vон	High-level output voltage	V <sub>IH</sub> = 2 V,	$I_{OH} = -75 \text{ mA},$	See Note 2	2.4	3.2		V
ЮН	High-level output current	V <sub>CC</sub> = 5 V, T <sub>A</sub> = 25°C,	V <sub>IH</sub> = 4.5 V, See Note 2	V <sub>OH</sub> = 2 V,	- 100	- 200	- 250	mA
loL	Low-level output current	V <sub>IL</sub> = 0.8 V,	$V_{OL} = 0.4 V$ ,	See Note 2			- 800	μΑ
IO(off)	Off-state output current	$V_{CC} = 3 V$ ,	V <sub>O</sub> = 3 V				500	μΑ
۱н	High-level input current	V <sub>I</sub> = 4.5 V					40	μΑ
I <sub>I</sub> L	Low-level input current	V <sub>I</sub> = 0.4 V					- 250	μΑ
los	Short-circuit output current	V <sub>CC</sub> = 5 V				-5	- 30	mA
ICCH	Supply current, outputs high	$V_{CC} = 5.25 \text{ V},$	All inputs at 2 V,	No load		9	14	mA
ICCL	Supply current, outputs low	$V_{CC} = 5.25 \text{ V},$	All inputs at 0.8 V,	No load		13	30	mA

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 5 \text{ V}$  and  $T_A = 25^{\circ}\text{C}$ .

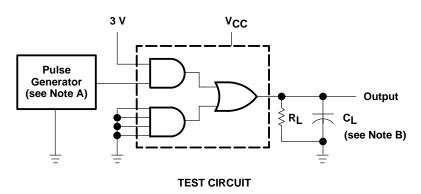
NOTE 2: The output voltage and current limits are ensured for any appropriate combination of high and low inputs specified by the function table for the desired output.

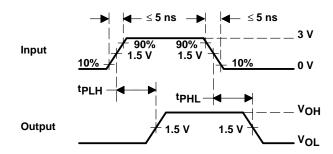
# switching characteristics over recommended ranges of supply voltage and operating free-air temperature

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
tPLH	Propagation delay time, low-to-high-level output	Rι = 37 Ω.	C <sub>I</sub> = 15 pF,	See Figure 1		6	14	ns
<sup>t</sup> PHL	Propagation delay time, high-to-low-level output	$RL = 37 \Omega$	CL = 15 pr,	See Figure 1		4	14	ns
<sup>t</sup> PLH	Propagation delay time, low-to-high-level output	P 27 O	$C_1 = 1000 pF$	See Figure 1		18	30	ns
tPHL	Propagation delay time, high-to-low-level output	$R_L = 37 \Omega$ ,	CL = 1000 pr,	See Figure 1		29	50	ns

 $<sup>\</sup>dagger$  All typical values are at V<sub>CC</sub> = 5 V and T<sub>A</sub> = 25°C.

#### PARAMETER MEASUREMENT INFORMATION





#### **VOLTAGE WAVEFORMS**

NOTES: A. The pulse generator has the following characteristics:  $Z_0 = 50 \Omega$ ,  $t_W = 200 \text{ ns}$ , duty cycle = 50%.

B. C<sub>L</sub> includes probe and jig capacitance.

Figure 1. Test Circuit and Voltage Waveforms



## **TYPICAL CHARACTERISTICS**

# OUTPUT CURRENT vs OUTPUT VOLTAGE

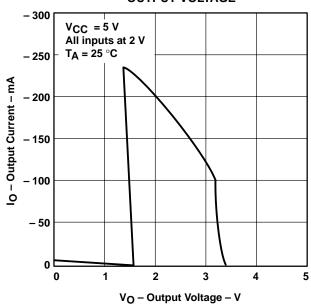


Figure 2

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